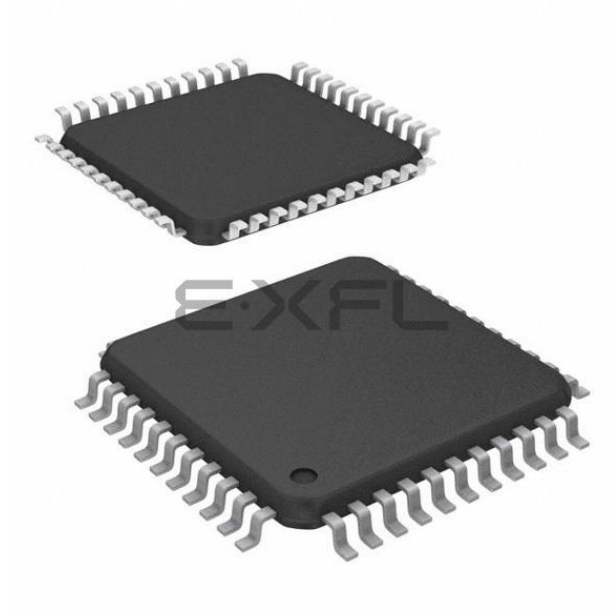

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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	M8C
Core Size	8-Bit
Speed	24MHz
Connectivity	I²C, IrDA, SPI, UART/USART
Peripherals	LVD, POR, PWM, WDT
Number of I/O	40
Program Memory Size	16KB (16K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	1K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.25V
Data Converters	A/D 4x14b; D/A 4x9b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	44-LQFP
Supplier Device Package	44-TQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/cy8c28545-24axit

PSoC Functional Overview

The PSoC family consists of many devices with On-Chip Controllers. These devices are designed to replace multiple traditional MCU based system components with one low cost single chip programmable component. A PSoC device includes configurable analog blocks, digital blocks, and interconnections. This architecture enables the user to create customized peripheral configurations to match the requirements of each individual application. In addition, a fast CPU, Flash program memory, SRAM data memory, and configurable I/O are included in a range of convenient pinouts and packages.

The CY8C28xxx group of PSoC devices described in this datasheet have multiple resource configuration options available. Therefore, not every resource mentioned in this datasheet is available for each CY8C28xxx subgroup. The CY8C28x45 subgroup has a full feature set of all resources described. There are six more segmented subgroups that allow designers to use a device with only the resources and functionality necessary for a specific application. See Table 2 on page 9 to determine the resources available for each CY8C28xxx subgroup. The same information is also presented in more detail in the Ordering Information section.

The architecture for this specific PSoC device family, as shown in the Logic Block Diagram on page 1, consists of four main areas: PSoC Core, Digital System, Analog System, and System Resources. The configurable global bus system allows all the device resources to be combined into a complete custom system. PSoC CY8C28xxx family devices have up to six I/O ports that connect to the global digital and analog interconnects, providing access to up to 12 digital blocks and up to 16 analog blocks.

The PSoC Core

The PSoC Core is a powerful engine that supports a rich feature set. The core includes a CPU, memory, clocks, and configurable general Purpose I/O (GPIO). The M8C CPU core is a powerful processor with speeds up to 24 MHz, providing a four MIPS 8-bit Harvard architecture microcontroller.

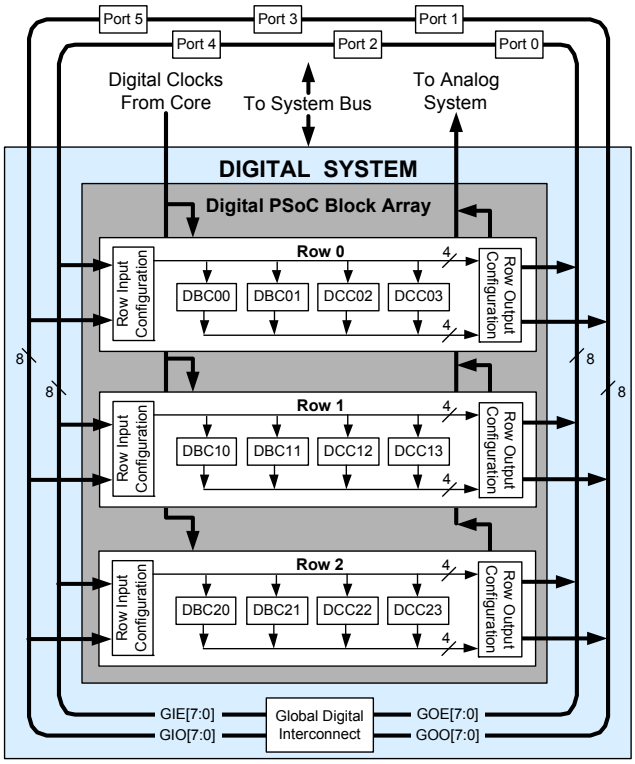
Memory encompasses 16K bytes of Flash for program storage, 1K bytes of SRAM for data storage. The PSoC device incorporates flexible internal clock generators, including a 24 MHz internal main oscillator (IMO) accurate to 2.5% over temperature and voltage. A low power 32 kHz internal low speed oscillator (ILO) is provided for the sleep timer and watch dog timer (WDT). The 32.768 kHz external crystal oscillator (ECO) is available for use as a real time clock (RTC) and can optionally generate a crystal-accurate 24 MHz system clock using a PLL.

PSoC GPIOs provide connections to the CPU, and digital and analog resources. Each pin's drive mode may be selected from 8 options, which allows great flexibility in external interfacing. Every pin also has the capability to generate a system interrupt on high level, low level, and change from last read.

The Digital System

The Digital System is composed of up to 12 configurable digital PSoC blocks. Each block is an 8-bit resource that can be used alone or combined with other blocks to create 8, 16, 24, and 32-bit peripherals, which are called user modules. The digital blocks can be connected to any GPIO through a series of global buses that can route any signal to any pin.

Figure 2. Digital System Block Diagram[1]



Digital peripheral configurations include:

- PWMs (8- and 16-bit, One-shot and Multi-shot capability)
- PWMs with Dead band/Kill (8- and 16-bit)
- Counters (8 to 32 bit)
- Timers (8 to 32 bit)
- Full-duplex 8-bit UARTs (up to 3) with selectable parity
- Half-duplex 8-bit UARTs (up to 6) with selectable parity
- Variable length SPI slave and master
  - Up to 6 total slaves and masters (8-bit)
  - Supports 8 to 16 bit operation
- I^2C slave, master, or multi-master (up to 2 available as System Resources)
- IrDA (up to 3)
- Pseudo Random Sequence Generators (8 to 32 bit)
- Cyclical Redundancy Checker/Generator (16 bit)
- Shift Register (2 to 32 bit)

Note
1. CY8C28x52 devices do not have digital block row 2. They have two digital rows with eight total digital blocks.

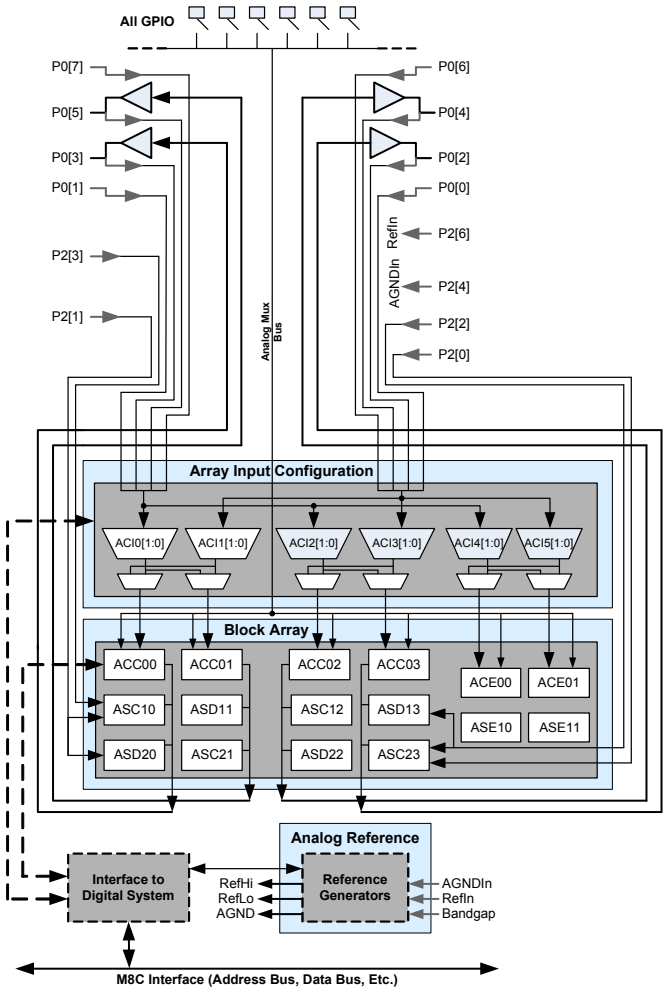
The Analog System

The Analog System is composed of up to 16 configurable analog blocks, each containing an opamp circuit that allows the creation of complex analog signal flows. Some devices in this PSoC family have an analog multiplex bus that can connect to every GPIO pin. This bus can also connect to the analog system for analysis with comparators and analog-to-digital converters. It can be split into two sections for simultaneous dual-channel processing.

Some of the more common PSoC analog functions (most available as user modules) are:

- Analog-to-digital converters (6 to 14-bit resolution, up to 4, selectable as Incremental or Delta Sigma)
- Dedicated 10-bit SAR ADC with sample rates up to 142 ksps
- Synchronized, simultaneous Delta Sigma ADCs (up to 4)
- Filters (2 to 8 pole band-pass, low pass, and notch)
- Amplifiers (up to 4, with selectable gain to 48x)
- Instrumentation amplifiers (up to 2, with selectable gain to 93x)
- Comparators (up to 6, with 16 selectable thresholds)
- DACs (up to 4, with 6 to 9-bit resolution)
- Multiplying DACs (up to 4, with 6 to 9-bit resolution)
- High current output drivers (up to 4 with 30 mA drive)
- 1.3 V reference (as a System Resource)
- DTMF Dialer
- Modulators
- Correlators
- Peak detectors
- Many other topologies possible

Figure 3. Analog System Block Diagram for CY8C28x45 and CY8C28x52 Devices



Designing with PSoC Designer

The development process for the PSoC device differs from that of a traditional fixed-function microprocessor. The configurable analog and digital hardware blocks give the PSoC architecture a unique flexibility that pays dividends in managing specification change during development and lowering inventory costs. These configurable resources, called PSoC blocks, have the ability to implement a wide variety of user-selectable functions. The PSoC development process is:

1. Select user modules.
2. Configure user modules.
3. Organize and connect.
4. Generate, verify, and debug.

Select User Modules

PSoC Designer provides a library of prebuilt, pretested hardware peripheral components called “user modules.” User modules make selecting and implementing peripheral devices, both analog and digital, simple.

Configure User Modules

Each user module that you select establishes the basic register settings that implement the selected function. They also provide parameters and properties that allow you to tailor their precise configuration to your particular application. For example, a PWM User Module configures one or more digital PSoC blocks, one for each eight bits of resolution. Using these parameters, you can establish the pulse width and duty cycle. Configure the parameters and properties to correspond to your chosen application. Enter values directly or by selecting values from drop-down menus. All of the user modules are documented in datasheets that may be viewed directly in PSoC Designer or on the Cypress website. These user module datasheets explain the internal operation of the user module and provide performance specifications. Each datasheet describes the use of each user module parameter, and other information that you may need to successfully implement your design.

Organize and Connect

Build signal chains at the chip level by interconnecting user modules to each other and the I/O pins. Perform the selection, configuration, and routing so that you have complete control over all on-chip resources.

Generate, Verify, and Debug

When you are ready to test the hardware configuration or move on to developing code for the project, perform the “Generate Configuration Files” step. This causes PSoC Designer to generate source code that automatically configures the device to your specification and provides the software for the system. The generated code provides APIs with high-level functions to control and respond to hardware events at run time, and interrupt service routines that you can adapt as needed.

A complete code development environment lets you to develop and customize your applications in C, assembly language, or both.

The last step in the development process takes place inside PSoC Designer's Debugger (accessed by clicking the Connect icon). PSoC Designer downloads the HEX image to the ICE where it runs at full-speed. PSoC Designer debugging capabilities rival those of systems costing many times more. In addition to traditional single-step, run-to-breakpoint, and watch-variable features, the debug interface provides a large trace buffer. It lets you to define complex breakpoint events that include monitoring address and data bus values, memory locations, and external signals.

Table 9. CY8C28x03 Register Map Bank 1 Table: Configuration Space

Name	Addr (1,Hex)	Access	Name	Addr (1,Hex)	Access	Name	Addr (1,Hex)	Access	Name	Addr (1,Hex)	Access
PRT0DM0	00	RW	DBC20FN	40	RW		80		RDI2RI	C0	RW
PRT0DM1	01	RW	DBC20IN	41	RW	SADC_TSCMPL	81	RW	RDI2SYN	C1	RW
PRT0IC0	02	RW	DBC20OU	42	RW	SADC_TSCMPH	82	RW	RDI2IS	C2	RW
PRT0IC1	03	RW	DBC20CR1	43	RW		83		RDI2LT0	C3	RW
PRT1DM0	04	RW	DBC21FN	44	RW		84		RDI2LT1	C4	RW
PRT1DM1	05	RW	DBC21IN	45	RW		85		RDI2RO0	C5	RW
PRT1IC0	06	RW	DBC21OU	46	RW		86		RDI2RO1	C6	RW
PRT1IC1	07	RW	DBC21CR1	47	RW		87		RDI2DSM	C7	RW
PRT2DM0	08	RW	DCC22FN	48	RW		88			C8	
PRT2DM1	09	RW	DCC22IN	49	RW		89			C9	
PRT2IC0	0A	RW	DCC22OU	4A	RW		8A			CA	
PRT2IC1	0B	RW	DCC22CR1	4B	RW		8B			CB	
PRT3DM0	0C	RW	DCC23FN	4C	RW		8C			CC	
PRT3DM1	0D	RW	DCC23IN	4D	RW		8D			CD	
PRT3IC0	0E	RW	DCC23OU	4E	RW		8E			CE	
PRT3IC1	0F	RW	DCC23CR1	4F	RW		8F			CF	
PRT4DM0	10	RW		50			90		GDI_O_IN	D0	RW
PRT4DM1	11	RW		51			91		GDI_E_IN	D1	RW
PRT4IC0	12	RW		52			92		GDI_O_OU	D2	RW
PRT4IC1	13	RW		53			93		GDI_E_OU	D3	RW
PRT5DM0	14	RW		54			94			D4	
PRT5DM1	15	RW		55			95			D5	
PRT5IC0	16	RW		56			96			D6	
PRT5IC1	17	RW		57			97			D7	
	18			58			98			D8	
	19			59			99			D9	
	1A			5A			9A			DA	
	1B			5B			9B			DB	
	1C			5C			9C			DC	
	1D			5D			9D		OSC_GO_EN	DD	RW
	1E			5E			9E		OSC_CR4	DE	RW
	1F			5F			9F		OSC_CR3	DF	RW
DBC00FN	20	RW		60		GDI_O_IN_CR	A0	RW	OSC_CR0	E0	RW
DBC00IN	21	RW		61		GDI_E_IN_CR	A1	RW	OSC_CR1	E1	RW
DBC00OU	22	RW		62		GDI_O_OU_CR	A2	RW	OSC_CR2	E2	RW
DBC00CR1	23	RW		63		GDI_E_OU_CR	A3	RW	VLT_CR	E3	RW
DBC01FN	24	RW		64		RTC_H	A4	RW	VLT_CMP	E4	RW
DBC01IN	25	RW		65		RTC_M	A5	RW		E5	
DBC01OU	26	RW		66		RTC_S	A6	RW		E6	
DBC01CR1	27	RW		67		RTC_CR	A7	RW		E7	
DCC02FN	28	RW		68		SADC_CR0	A8	RW	IMO_TR	E8	RW
DCC02IN	29	RW		69		SADC_CR1	A9	RW	ILO_TR	E9	RW
DCC02OU	2A	RW		6A		SADC_CR2	AA	RW	BDG_TR	EA	RW
DCC02CR1	2B	RW	I2C1_CFG	6B	RW	SADC_CR3	AB	RW	ECO_TR	EB	RW
DCC03FN	2C	RW	TMP_DR0	6C	RW	SADC_CR4	AC	RW		EC	
DCC03IN	2D	RW	TMP_DR1	6D	RW	I2C0_ADDR	AD	RW		ED	
DCC03OU	2E	RW	TMP_DR2	6E	RW	I2C1_ADDR	AE	RW		EE	
DCC03CR1	2F	RW	TMP_DR3	6F	RW	AMUX_CLK	AF	RW		EF	
DBC10FN	30	RW		70		RDI0RI	B0	RW		F0	
DBC10IN	31	RW	SADC_TSCR0	71	RW	RDI0SYN	B1	RW		F1	
DBC10OU	32	RW	SADC_TSCR1	72	RW	RDI0IS	B2	RW		F2	
DBC10CR1	33	RW		73		RDI0LT0	B3	RW		F3	
DBC11FN	34	RW		74		RDI0LT1	B4	RW		F4	
DBC11IN	35	RW		75		RDI0RO0	B5	RW		F5	
DBC11OU	36	RW		76		RDI0RO1	B6	RW		F6	
DBC11CR1	37	RW		77		RDIODSM	B7	RW	CPU_F	F7	RL
DCC12FN	38	RW		78		RDI1RI	B8	RW		F8	
DCC12IN	39	RW		79		RDI1SYN	B9	RW		F9	
DCC12OU	3A	RW		7A		RDI1IS	BA	RW	FLS_PR1	FA	RW
DCC12CR1	3B	RW		7B		RDI1LT0	BB	RW		FB	
DCC13FN	3C	RW		7C		RDI1LT1	BC	RW		FC	
DCC13IN	3D	RW		7D		RDI1RO0	BD	RW		FD	
DCC13OU	3E	RW		7E		RDI1RO1	BE	RW	CPU_SCR1	FE	#
DCC13CR1	3F	RW		7F		RDI1DSM	BF	RW	CPU_SCR0	FF	#

Blank fields are Reserved and should not be accessed. # Access is bit specific. *Address has a dual purpose, see “Mapping Exceptions” on page 251

Table 10. CY8C28x13 Register Map Bank 0 Table: User Space

Name	Addr (0,Hex)	Access	Name	Addr (0,Hex)	Access	Name	Addr (0,Hex)	Access	Name	Addr (0,Hex)	Access
PRT0DR	00	RW	DBC20DR0	40	#		80		RDI2RI	C0	RW
PRT0IE	01	RW	DBC20DR1	41	W		81		RDI2SYN	C1	RW
PRT0GS	02	RW	DBC20DR2	42	RW		82		RDI2IS	C2	RW
PRT0DM2	03	RW	DBC20CR0	43	#		83		RDI2LT0	C3	RW
PRT1DR	04	RW	DBC21DR0	44	#		84		RDI2LT1	C4	RW
PRT1IE	05	RW	DBC21DR1	45	W		85		RDI2RO0	C5	RW
PRT1GS	06	RW	DBC21DR2	46	RW		86		RDI2RO1	C6	RW
PRT1DM2	07	RW	DBC21CR0	47	#		87		RDI2DSM	C7	RW
PRT2DR	08	RW	DCC22DR0	48	#		88			C8	
PRT2IE	09	RW	DCC22DR1	49	W		89			C9	
PRT2GS	0A	RW	DCC22DR2	4A	RW		8A			CA	
PRT2DM2	0B	RW	DCC22CR0	4B	#		8B			CB	
PRT3DR	0C	RW	DCC23DR0	4C	#		8C			CC	
PRT3IE	0D	RW	DCC23DR1	4D	W		8D			CD	
PRT3GS	0E	RW	DCC23DR2	4E	RW		8E			CE	
PRT3DM2	0F	RW	DCC23CR0	4F	#		8F			CF	
PRT4DR	10	RW		50			90		CUR_PP	D0	RW
PRT4IE	11	RW		51			91		STK_PP	D1	RW
PRT4GS	12	RW		52			92			D2	
PRT4DM2	13	RW		53			93		IDX_PP	D3	RW
PRT5DR	14	RW		54			94		MVR_PP	D4	RW
PRT5IE	15	RW		55			95		MVW_PP	D5	RW
PRT5GS	16	RW		56			96		I2C0_CFG	D6	RW
PRT5DM2	17	RW		57			97		I2C0_SCR	D7	#
	18			58			98		I2C0_DR	D8	RW
	19			59			99		I2C0_MSCR	D9	#
	1A			5A			9A		INT_CLR0	DA	RW
	1B			5B			9B		INT_CLR1	DB	RW
	1C			5C			9C		INT_CLR2	DC	RW
	1D			5D			9D		INT_CLR3	DD	RW
	1E			5E			9E		INT_MSK3	DE	RW
	1F			5F			9F		INT_MSK2	DF	RW
DBC00DR0	20	#		60		DEC0_DH	A0	RC	INT_MSK0	E0	RW
DBC00DR1	21	W	AMUX_CFG	61	RW	DEC0_DL	A1	RC	INT_MSK1	E1	RW
DBC00DR2	22	RW		62		DEC1_DH	A2	RC	INT_VC	E2	RC
DBC00CR0	23	#		63		DEC1_DL	A3	RC	RES_WDT	E3	W
DBC01DR0	24	#		64			A4			E4	
DBC01DR1	25	W		65			A5			E5	
DBC01DR2	26	RW		66			A6		DEC_CR0*	E6	RW
DBC01CR0	27	#		67			A7		DEC_CR1*	E7	RW
DCC02DR0	28	#		68		MUL1_X	A8	W	MUL0_X	E8	W
DCC02DR1	29	W		69		MUL1_Y	A9	W	MUL0_Y	E9	W
DCC02DR2	2A	RW	SADC_DH	6A	RW	MUL1_DH	AA	R	MUL0_DH	EA	R
DCC02CR0	2B	#	SADC_DL	6B	RW	MUL1_DL	AB	R	MUL0_DL	EB	R
DCC03DR0	2C	#	TMP_DR0	6C	RW	ACC1_DR1	AC	RW	ACC0_DR1	EC	RW
DCC03DR1	2D	W	TMP_DR1	6D	RW	ACC1_DR0	AD	RW	ACC0_DR0	ED	RW
DCC03DR2	2E	RW	TMP_DR2	6E	RW	ACC1_DR3	AE	RW	ACC0_DR3	EE	RW
DCC03CR0	2F	#	TMP_DR3	6F	RW	ACC1_DR2	AF	RW	ACC0_DR2	EF	RW
DBC10DR0	30	#		70		RDI0RI	B0	RW		F0	
DBC10DR1	31	W		71		RDI0SYN	B1	RW		F1	
DBC10DR2	32	RW		72		RDI0IS	B2	RW		F2	
DBC10CR0	33	#		73		RDI0LT0	B3	RW		F3	
DBC11DR0	34	#		74		RDI0LT1	B4	RW		F4	
DBC11DR1	35	W		75		RDI0RO0	B5	RW		F5	
DBC11DR2	36	RW		76		RDI0RO1	B6	RW		F6	
DBC11CR0	37	#		77		RDI0DSM	B7	RW	CPU_F	F7	RL
DCC12DR0	38	#		78		RDI1RI	B8	RW		F8	
DCC12DR1	39	W		79		RDI1SYN	B9	RW		F9	
DCC12DR2	3A	RW		7A		RDI1IS	BA	RW		FA	
DCC12CR0	3B	#		7B		RDI1LT0	BB	RW		FB	
DCC13DR0	3C	#		7C		RDI1LT1	BC	RW	DAC1_D	FC	RW
DCC13DR1	3D	W		7D		RDI1RO0	BD	RW	DAC0_D	FD	RW
DCC13DR2	3E	RW		7E		RDI1RO1	BE	RW	CPU_SCR1	FE	#
DCC13CR0	3F	#		7F		RDI1DSM	BF	RW	CPU_SCR0	FF	#

Blank fields are Reserved and should not be accessed. # Access is bit specific. *Address has a dual purpose, see “Mapping Exceptions” on page 251

Table 21. CY8C28x52 Register Map Bank 1 Table: Configuration Space

Name	Addr (1,Hex)	Access	Name	Addr (1,Hex)	Access	Name	Addr (1,Hex)	Access	Name	Addr (1,Hex)	Access
PRT0DM0	00	RW		40			80			C0	
PRT0DM1	01	RW		41			81			C1	
PRT0IC0	02	RW		42			82			C2	
PRT0IC1	03	RW		43		ACE_AMD_CR1	83	RW		C3	
PRT1DM0	04	RW		44			84			C4	
PRT1DM1	05	RW		45		ACE_PWM_CR	85	RW		C5	
PRT1IC0	06	RW		46		ACE_ADC0_CR	86	RW		C6	
PRT1IC1	07	RW		47		ACE_ADC1_CR	87	RW		C7	
PRT2DM0	08	RW		48			88			C8	
PRT2DM1	09	RW		49		ACE_CLK_CR0	89	RW		C9	
PRT2IC0	0A	RW		4A		ACE_CLK_CR1	8A	RW		CA	
PRT2IC1	0B	RW		4B		ACE_CLK_CR3	8B	RW		CB	
PRT3DM0	0C	RW		4C			8C			CC	
PRT3DM1	0D	RW		4D		ACE01CR1	8D	RW		CD	
PRT3IC0	0E	RW		4E		ACE01CR2	8E	RW		CE	
PRT3IC1	0F	RW		4F		ASE11CR0	8F	RW		CF	
PRT4DM0	10	RW		50			90		GDI_O_IN	D0	RW
PRT4DM1	11	RW		51		DEC0_CR0	91	RW	GDI_E_IN	D1	RW
PRT4IC0	12	RW		52		DEC_CR3	92	RW	GDI_O_OU	D2	RW
PRT4IC1	13	RW		53			93		GDI_E_OU	D3	RW
PRT5DM0	14	RW		54			94		DEC0_CR	D4	RW
PRT5DM1	15	RW		55		DEC1_CR0	95	RW	DEC1_CR	D5	RW
PRT5IC0	16	RW		56		DEC_CR4	96	RW	DEC2_CR	D6	RW
PRT5IC1	17	RW		57			97		DEC3_CR	D7	RW
	18			58			98		MUX_CR0	D8	RW
	19			59		DEC2_CR0	99	RW	MUX_CR1	D9	RW
	1A			5A		DEC_CR5	9A	RW	MUX_CR2	DA	RW
	1B			5B			9B		MUX_CR3	DB	RW
	1C			5C			9C		IDAC_CR1	DC	RW
	1D			5D		DEC3_CR0	9D	RW	OSC_GO_EN	DD	RW
	1E			5E			9E		OSC_CR4	DE	RW
	1F			5F			9F		OSC_CR3	DF	RW
DBC00FN	20	RW	CLK_CR0	60	RW	GDI_O_IN_CR	A0	RW	OSC_CR0	E0	RW
DBC00IN	21	RW	CLK_CR1	61	RW	GDI_E_IN_CR	A1	RW	OSC_CR1	E1	RW
DBC00OU	22	RW	ABF_CR0	62	RW	GDI_O_OU_CR	A2	RW	OSC_CR2	E2	RW
DBC00CR1	23	RW	AMD_CR0	63	RW	GDI_E_OU_CR	A3	RW	VLT_CR	E3	RW
DBC01FN	24	RW	CMP_GO_EN	64	RW	RTC_H	A4	RW	VLT_CMP	E4	RW
DBC01IN	25	RW	CMP_GO_EN1	65	RW	RTC_M	A5	RW	ADC0_TR	E5	RW
DBC01OU	26	RW	AMD_CR1	66	RW	RTC_S	A6	RW	ADC1_TR	E6	RW
DBC01CR1	27	RW	ALT_CR0	67	RW	RTC_CR	A7	RW	IDAC_CR2	E7	RW
DCC02FN	28	RW	ALT_CR1	68	RW		A8		IMO_TR	E8	RW
DCC02IN	29	RW	CLK_CR2	69	RW		A9		ILO_TR	E9	RW
DCC02OU	2A	RW	AMUX_CFG1	6A	RW		AA		BDG_TR	EA	RW
DCC02CR1	2B	RW		6B			AB		ECO_TR	EB	RW
DCC03FN	2C	RW	TMP_DR0	6C	RW		AC		MUX_CR4	EC	RW
DCC03IN	2D	RW	TMP_DR1	6D	RW	I2C0_ADDR	AD	RW	MUX_CR5	ED	RW
DCC03OU	2E	RW	TMP_DR2	6E	RW		AE			EE	
DCC03CR1	2F	RW	TMP_DR3	6F	RW	AMUX_CLK	AF	RW		EF	
DBC10FN	30	RW		70		RDI0RI	B0	RW		F0	
DBC10IN	31	RW		71		RDI0SYN	B1	RW		F1	
DBC10OU	32	RW		72		RDI0IS	B2	RW		F2	
DBC10CR1	33	RW	ACE_AMD_CR0	73	RW	RDI0LT0	B3	RW		F3	
DBC11FN	34	RW		74		RDI0LT1	B4	RW		F4	
DBC11IN	35	RW	ACE_AMX_IN	75	RW	RDI0RO0	B5	RW		F5	
DBC11OU	36	RW	ACE_CMP_CR0	76	RW	RDI0RO1	B6	RW		F6	
DBC11CR1	37	RW	ACE_CMP_CR1	77	RW	RDIODSM	B7	RW	CPU_F	F7	RL
DCC12FN	38	RW		78		RDI1RI	B8	RW		F8	
DCC12IN	39	RW	ACE_CMP_GI_EN	79	RW	RDI1SYN	B9	RW		F9	
DCC12OU	3A	RW	ACE_ALT_CR0	7A	RW	RDI1IS	BA	RW	FLS_PR1	FA	RW
DCC12CR1	3B	RW	ACE_ABF_CR0	7B	RW	RDI1LT0	BB	RW		FB	
DCC13FN	3C	RW		7C		RDI1LT1	BC	RW		FC	
DCC13IN	3D	RW	ACE0_CR1	7D	RW	RDI1RO0	BD	RW	IDAC_CR0	FD	RW
DCC13OU	3E	RW	ACE0_CR2	7E	RW	RDI1RO1	BE	RW	CPU_SCR1	FE	#
DCC13CR1	3F	RW	ACE0_CR3	7F	RW	RDI1DSM	BF	RW	CPU_SCR0	FF	#

Blank fields are Reserved and should not be accessed. # Access is bit specific. *Address has a dual purpose, see “Mapping Exceptions” on page 251

Absolute Maximum Ratings

Table 22. Absolute Maximum Ratings

Symbol	Description	Min	Typ	Max	Units	Notes
T_{STG}	Storage temperature	–55	25	+100	°C	Higher storage temperatures reduce data retention time. Recommended storage temperature is +25°C ± 25°C. Extended duration storage temperatures above 65°C degrade reliability.
$T_{BAKETEMP}$	Bake temperature	–	125	See Package label	°C	
$t_{BAKETIME}$	Bake time	See package label	-	72	Hours	
T_A	Ambient temperature with power applied	-40	–	+85	°C	
V_{DD}	Supply voltage on V_{DD} relative to V_{SS}	-0.5	–	+6.0	V	
V_{IO}	DC input voltage	V_{SS} – 0.5	–	V_{DD} + 0.5	V	
V_{IOZ}	DC voltage applied to tri-state	V_{SS} – 0.5	–	V_{DD} + 0.5	V	
I_{MIO}	Maximum current into any port pin	-25	–	+50	mA	
I_{MAIO}	Maximum current into any port pin configured as analog driver	-50	–	+50	mA	
ESD	Electro static discharge voltage	2000	–	–	V	Human Body Model ESD.
LU	Latch up current	–	–	200	mA	

Operating Temperature

Table 23. Operating Temperature

Symbol	Description	Min	Typ	Max	Units	Notes
T_A	Ambient temperature	-40	–	+85	°C	
T_J	Junction temperature	-40	–	+100	°C	The temperature rise from ambient to junction is package specific. See Thermal Impedances on page 72. The user must limit the power consumption to comply with this requirement.

DC Electrical Characteristics

DC Chip Level Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 24. DC Chip Level Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
V_{DD}	Supply voltage	3.00	–	5.25	V	
I_{DD}	Supply current	–	8	14	mA	Conditions are V_{DD} = 5.0 V, T_A = 25 °C, CPU = 3 MHz, SYSCLK doubler disabled. VC1 = 1.5 MHz, VC2 = 93.75 kHz, VC3 = 93.75 kHz.
I_{DD3}	Supply current	–	5	9	mA	Conditions are V_{DD} = 3.3 V, T_A = 25 °C, CPU = 3 MHz, SYSCLK doubler disabled. VC1 = 1.5 MHz, VC2 = 93.75 kHz, VC3 = 93.75 kHz.
I_{DDP}	Supply current when IMO = 6 MHz using SLIMO mode=1	–	2	3	mA	Conditions are V_{DD} = 3.3 V, T_A = 25 °C, CPU = 0.75 MHz, SYSCLK doubler disabled, VC1 = 0.375 MHz, VC2 = 23.44 kHz, VC3 = 0.09 kHz.
I_{SB}	Sleep (Mode) current with POR, LVD, sleep timer, and WDT.[12]	–	3	10	µA	Conditions are with internal slow speed oscillator, V_{DD} = 3.3 V, –40 °C ≤ T_A ≤ 55 °C.
I_{SBH}	Sleep (Mode) current with POR, LVD, sleep timer, and WDT at high temperature.[12]	–	4	25	µA	Conditions are with internal slow speed oscillator, V_{DD} = 3.3 V, 55 °C < T_A ≤ 85 °C.
I_{SBXTL}	Sleep (Mode) Current with POR, LVD, sleep timer, WDT, and external crystal.[12]	–	4	13	µA	Conditions are with properly loaded, 1 µW max, 32.768 kHz crystal. V_{DD} = 3.3 V, –40 °C ≤ T_A ≤ 55 °C.
I_{SBXTLH}	Sleep (Mode) current with POR, LVD, sleep timer, WDT, and external crystal at high temperature.[12]	–	5	26	µA	Conditions are with properly loaded, 1 µW max, 32.768 kHz crystal. V_{DD} = 3.3 V, 55 °C < T_A ≤ 85 °C.
I_{SBRTC}	Current consumed by RTC during sleep	–	0.5	1	µA	Extra current consumed by the RTC during sleep. This number is typical at 25 °C and 5 V.
V_{REF}	Reference voltage (Bandgap)	1.280	1.300	1.320	V	Trimmed for appropriate V_{DD}.
I_{SXRES}	Supply current with XRES asserted 5 V	–	0.65	3	mA	Max is peak current after XRES; Typical value is the steady state current value. T_A = 25 °C.
	Supply current with XRES asserted 3.3 V	-	0.4	1.5	mA	

Note
12. Standby (sleep) current includes all functions (POR, LVD, WDT, Sleep Timer) needed for reliable system operation. This should be compared with devices that have similar functions enabled.

DC GPIO Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 25. DC GPIO Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
R_{PU}	Pull-up resistor	4	5.6	8	kΩ	
R_{PD}	Pull-down resistor	4	5.6	8	kΩ	
V_{OH}	High output level	V_{DD} – 1.0	–	–	V	I_{OH} = 10 mA, V_{DD} = 4.75 to 5.25 V (8 total loads, 4 on even port pins (for example, P0[2], P1[4]), 4 on odd port pins (for example, P0[3], P1[5])). 80 mA maximum combined I_{OH} budget.
V_{OL}	Low output level	–	–	0.75	V	I_{OL} = 25 mA, V_{DD} = 4.75 to 5.25 V (8 total loads, 4 on even port pins (for example, P0[2], P1[4]), 4 on odd port pins (for example, P0[3], P1[5])). 150 mA maximum combined I_{OL} budget.
I_{OH}	High level source current	10	–	–	mA	V_{OH} = V_{DD} – 1.0 V, see the limitations of the total current in the note for V_{OH}.
I_{OL}	Low level sink current	25	–	–	mA	V_{OL} = 0.75 V, see the limitations of the total current in the note for V_{OL}.
V_{IL}	Input low level	–	–	0.8	V	V_{DD} = 3.0 to 5.25.
V_{IH}	Input high level	2.1	–	–	V	V_{DD} = 3.0 to 5.25.
V_H	Input hysteresis	–	60	–	mV	
I_{IL}	Input leakage (absolute value)	–	1	–	nA	Gross tested to 1 μA.
C_{IN}	Capacitive load on pins as input	–	3.5	10	pF	Package and pin dependent. Temp = 25 °C.
C_{OUT}	Capacitive load on pins as output	–	3.5	10	pF	Package and pin dependent. Temp = 25 °C.

DC Analog Output Buffer Specifications

The following tables list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 31. 5 V DC Analog Output Buffer Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
C_L	Load capacitance	–	–	200	pF	This specification applies to the external circuit that is being driven by the analog output buffer.
V_{OSOB}	Input offset voltage (Absolute Value)	–	3	12	mV	
TCV_{OSOB}	Average input offset voltage drift	–	+6	20	µV/°C	
V_{CMOB}	Common-mode input voltage range	0.5	–	V_{DD} – 1.0	V	
R_{OUTOB}	Output resistance Power = Low Power = High	 – –	 1 1	 – –	 Ω Ω	
$V_{OHIGHOB}$	High output voltage swing (Load = 32 Ω to V_{DD}/2) Power = Low Power = High	 0.5 × V_{DD} + 1.3 0.5 × V_{DD} + 1.3	 – –	 – –	 V V	
V_{OLOWOB}	Low output voltage swing (Load = 32 Ω to V_{DD}/2) Power = Low Power = High	 – –	 – –	 0.5 × V_{DD} – 1.3 0.5 × V_{DD} – 1.3	 V V	
I_{SOB}	Supply current including bias cell (No Load) Power = Low Power = High	 – –	 1.1 2.6	 5.1 8.8	 mA mA	
$PSRR_{OB}$	Supply voltage rejection ratio	53	64	–	dB	(0.5 × V_{DD} – 1.0) ≤ V_{OUT} ≤ (0.5 × V_{DD} + 0.9).

Table 34. 5-V DC Analog Reference Specifications *(continued)*

Reference ARF_CR [5:3]	Reference Power Settings	Symbol	Reference	Description	Min	Typ	Max	Units
0b001	RefPower = High Opamp bias = High	V_{REFHI}	Ref high	P2[4]+P2[6] (P2[4] = V_{DD}/2, P2[6] = 1.3 V)	P2[4] + P2[6] – 0.055	P2[4] + P2[6] – 0.019	P2[4] + P2[6] + 0.019	V
		V_{AGND}	AGND	P2[4]	P2[4]	P2[4]	P2[4]	–
		V_{REFLO}	Ref low	P2[4]–P2[6] (P2[4] = V_{DD}/2, P2[6] = 1.3 V)	P2[4] – P2[6] – 0.030	P2[4] – P2[6] + 0.005	P2[4] – P2[6] + 0.035	V
	RefPower = High Opamp bias = Low	V_{REFHI}	Ref high	P2[4]+P2[6] (P2[4] = V_{DD}/2, P2[6] = 1.3 V)	P2[4] + P2[6] – 0.05	P2[4] + P2[6] – 0.015	P2[4] + P2[6] + 0.021	V
		V_{AGND}	AGND	P2[4]	P2[4]	P2[4]	P2[4]	–
		V_{REFLO}	Ref low	P2[4]–P2[6] (P2[4] = V_{DD}/2, P2[6] = 1.3 V)	P2[4] – P2[6] – 0.033	P2[4] – P2[6] + 0.001	P2[4] – P2[6] + 0.031	V
	RefPower = Medium Opamp bias = High	V_{REFHI}	Ref high	P2[4]+P2[6] (P2[4] = V_{DD}/2, P2[6] = 1.3 V)	P2[4] + P2[6] – 0.048	P2[4] + P2[6] – 0.013	P2[4] + P2[6] + 0.022	V
		V_{AGND}	AGND	P2[4]	P2[4]	P2[4]	P2[4]	–
		V_{REFLO}	Ref low	P2[4]–P2[6] (P2[4] = V_{DD}/2, P2[6] = 1.3 V)	P2[4] – P2[6] – 0.034	P2[4] – P2[6] – 0.001	P2[4] – P2[6] + 0.031	V
	RefPower = Medium Opamp bias = Low	V_{REFHI}	Ref high	P2[4]+P2[6] (P2[4] = V_{DD}/2, P2[6] = 1.3 V)	P2[4] + P2[6] – 0.047	P2[4] + P2[6] – 0.012	P2[4] + P2[6] + 0.023	V
		V_{AGND}	AGND	P2[4]	P2[4]	P2[4]	P2[4]	–
		V_{REFLO}	Ref low	P2[4]–P2[6] (P2[4] = V_{DD}/2, P2[6] = 1.3 V)	P2[4] – P2[6] – 0.036	P2[4] – P2[6] – 0.002	P2[4] – P2[6] + 0.030	V
0b010	RefPower = High Opamp bias = High	V_{REFHI}	Ref high	V_{DD}	V_{DD} – 0.028	V_{DD} – 0.010	V_{DD}	V
		V_{AGND}	AGND	V_{DD}/2	V_{DD}/2 – 0.014	V_{DD}/2 – 0.002	V_{DD}/2 + 0.012	V
		V_{REFLO}	Ref low	V_{SS}	V_{SS}	V_{SS} + 0.004	V_{SS} + 0.008	V
	RefPower = High Opamp bias = Low	V_{REFHI}	Ref high	V_{DD}	V_{DD} – 0.021	V_{DD} – 0.007	V_{DD}	V
		V_{AGND}	AGND	V_{DD}/2	V_{DD}/2 – 0.014	V_{DD}/2 – 0.001	V_{DD}/2 + 0.012	V
		V_{REFLO}	Ref low	V_{SS}	V_{SS}	V_{SS} + 0.002	V_{SS} + 0.005	V
	RefPower = Medium Opamp bias = High	V_{REFHI}	Ref high	V_{DD}	V_{DD} – 0.019	V_{DD} – 0.006	V_{DD}	V
		V_{AGND}	AGND	V_{DD}/2	V_{DD}/2 – 0.014	V_{DD}/2 – 0.001	V_{DD}/2 + 0.012	V
		V_{REFLO}	Ref low	V_{SS}	V_{SS}	V_{SS} + 0.002	V_{SS} + 0.004	V
	RefPower = Medium Opamp bias = Low	V_{REFHI}	Ref high	V_{DD}	V_{DD} – 0.017	V_{DD} – 0.005	V_{DD}	V
		V_{AGND}	AGND	V_{DD}/2	V_{DD}/2 – 0.014	V_{DD}/2 – 0.001	V_{DD}/2 + 0.013	V
		V_{REFLO}	Ref low	V_{SS}	V_{SS}	V_{SS} + 0.001	V_{SS} + 0.003	V

Table 34. 5-V DC Analog Reference Specifications *(continued)*

Reference ARF_CR [5:3]	Reference Power Settings	Symbol	Reference	Description	Min	Typ	Max	Units
0b011	RefPower = High Opamp bias = High	V_{REFHI}	Ref high	3 × Bandgap	3.736	3.887	4.030	V
		V_{AGND}	AGND	2 × Bandgap	2.525	2.598	2.667	V
		V_{REFLO}	Ref low	Bandgap	1.265	1.302	1.335	V
	RefPower = High Opamp bias = Low	V_{REFHI}	Ref high	3 × Bandgap	3.747	3.894	4.034	V
		V_{AGND}	AGND	2 × Bandgap	2.528	2.601	2.668	V
		V_{REFLO}	Ref low	Bandgap	1.264	1.302	1.335	V
	RefPower = Medium Opamp bias = High	V_{REFHI}	Ref high	3 × Bandgap	3.749	3.897	4.035	V
		V_{AGND}	AGND	2 × Bandgap	2.529	2.602	2.668	V
		V_{REFLO}	Ref low	Bandgap	1.264	1.302	1.335	V
	RefPower = Medium Opamp bias = Low	V_{REFHI}	Ref high	3 × Bandgap	3.751	3.899	4.037	V
		V_{AGND}	AGND	2 × Bandgap	2.530	2.603	2.669	V
		V_{REFLO}	Ref low	Bandgap	1.264	1.302	1.335	V
0b100	RefPower = High Opamp bias = High	V_{REFHI}	Ref high	2 × Bandgap + P2[6] (P2[6] = 1.3 V)	2.483 – P2[6]	2.578 – P2[6]	2.669 – P2[6]	V
		V_{AGND}	AGND	2 × Bandgap	2.525	2.598	2.666	V
		V_{REFLO}	Ref low	2 × Bandgap – P2[6] (P2[6] = 1.3 V)	2.512 – P2[6]	2.602 – P2[6]	2.684 – P2[6]	V
	RefPower = High Opamp bias = Low	V_{REFHI}	Ref high	2 × Bandgap + P2[6] (P2[6] = 1.3 V)	2.495 – P2[6]	2.586 – P2[6]	2.673 – P2[6]	V
		V_{AGND}	AGND	2 × Bandgap	2.528	2.601	2.668	V
		V_{REFLO}	Ref low	2 × Bandgap – P2[6] (P2[6] = 1.3 V)	2.510 – P2[6]	2.602 – P2[6]	2.685 – P2[6]	V
	RefPower = Medium Opamp bias = High	V_{REFHI}	Ref high	2 × Bandgap + P2[6] (P2[6] = 1.3 V)	2.498 – P2[6]	2.589 – P2[6]	2.674 – P2[6]	V
		V_{AGND}	AGND	2 × Bandgap	2.529	2.601	2.668	V
		V_{REFLO}	Ref low	2 × Bandgap – P2[6] (P2[6] = 1.3 V)	2.509 – P2[6]	2.601 – P2[6]	2.685 – P2[6]	V
	RefPower = Medium Opamp bias = Low	V_{REFHI}	Ref high	2 × Bandgap + P2[6] (P2[6] = 1.3 V)	2.500 – P2[6]	2.591 – P2[6]	2.675 – P2[6]	V
		V_{AGND}	AGND	2 × Bandgap	2.530	2.603	2.669	V
		V_{REFLO}	Ref low	2 × Bandgap – P2[6] (P2[6] = 1.3 V)	2.508 – P2[6]	2.601 – P2[6]	2.686 – P2[6]	V

Table 35. 3.3-V DC Analog Reference Specifications *(continued)*

Reference ARF_CR [5:3]	Reference Power Settings	Symbol	Reference	Description	Min	Typ	Max	Units
0b101	RefPower = High Opamp bias = High	V_{REFHI}	Ref high	P2[4] + Bandgap ($P2[4] = V_{DD}/2$)	P2[4] + 1.226	P2[4] + 1.286	P2[4] + 1.343	V
		V_{AGND}	AGND	P2[4]	P2[4]	P2[4]	P2[4]	–
		V_{REFLO}	Ref low	P2[4] – Bandgap ($P2[4] = V_{DD}/2$)	P2[4] – 1.323	P2[4] – 1.293	P2[4] –1.262	V
	RefPower = High Opamp bias = Low	V_{REFHI}	Ref high	P2[4] + Bandgap ($P2[4] = V_{DD}/2$)	P2[4] + 1.232	P2[4] + 1.29	P2[4] + 1.344	V
		V_{AGND}	AGND	P2[4]	P2[4]	P2[4]	P2[4]	–
		V_{REFLO}	Ref low	P2[4] – Bandgap ($P2[4] = V_{DD}/2$)	P2[4] – 1.324	P2[4] – 1.296	P2[4] – 1.267	V
	RefPower = Medium Opamp bias = High	V_{REFHI}	Ref high	P2[4] + Bandgap ($P2[4] = V_{DD}/2$)	P2[4] + 1.233	P2[4] + 1.291	P2[4] + 1.345	V
		V_{AGND}	AGND	P2[4]	P2[4]	P2[4]	P2[4]	–
		V_{REFLO}	Ref low	P2[4] – Bandgap ($P2[4] = V_{DD}/2$)	P2[4] – 1.324	P2[4] – 1.298	P2[4] – 1.269	V
	RefPower = Medium Opamp bias = Low	V_{REFHI}	Ref high	P2[4] + Bandgap ($P2[4] = V_{DD}/2$)	P2[4] + 1.234	P2[4] + 1.292	P2[4] +1.345	V
		V_{AGND}	AGND	P2[4]	P2[4]	P2[4]	P2[4]	–
		V_{REFLO}	Ref low	P2[4] – Bandgap ($P2[4] = V_{DD}/2$)	P2[4] – 1.324	P2[4] – 1.299	P2[4] – 1.270	V
0b110	RefPower = High Opamp bias = High	V_{REFHI}	Ref high	2 × Bandgap	2.504	2.595	2.672	V
		V_{AGND}	AGND	Bandgap	1.262	1.301	1.336	V
		V_{REFLO}	Ref low	V_{SS}	V_{SS}	V_{SS} + 0.006	V_{SS} + 0.013	V
	RefPower = High Opamp bias = Low	V_{REFHI}	Ref high	2 × Bandgap	2.506	2.593	2.674	V
		V_{AGND}	AGND	Bandgap	1.262	1.301	1.336	V
		V_{REFLO}	Ref low	V_{SS}	V_{SS}	V_{SS} + 0.003	V_{SS} + 0.008	V
	RefPower = Medium Opamp bias = High	V_{REFHI}	Ref high	2 × Bandgap	2.506	2.594	2.675	V
		V_{AGND}	AGND	Bandgap	1.262	1.301	1.335	V
		V_{REFLO}	Ref low	V_{SS}	V_{SS}	V_{SS} + 0.002	V_{SS} + 0.007	V
	RefPower = Medium Opamp bias = Low	V_{REFHI}	Ref high	2 × Bandgap	2.507	2.595	2.675	V
		V_{AGND}	AGND	Bandgap	1.262	1.301	1.335	V
		V_{REFLO}	Ref low	V_{SS}	V_{SS}	V_{SS} + 0.001	V_{SS} + 0.005	V
0b111	All power settings. Not allowed for 3.3 V.	–	–	–	–	–	–	–

Figure 10. PLL Lock Timing Diagram

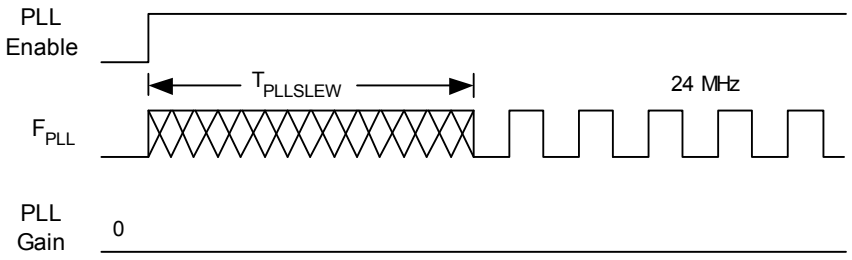


Figure 11. PLL Lock for Low Gain Setting Timing Diagram

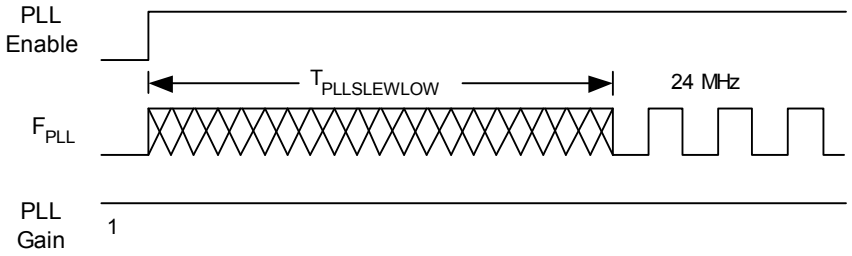


Figure 12. External Crystal Oscillator Startup Timing Diagram

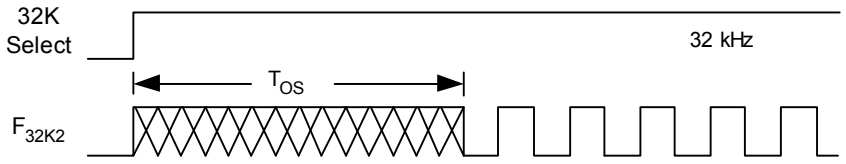
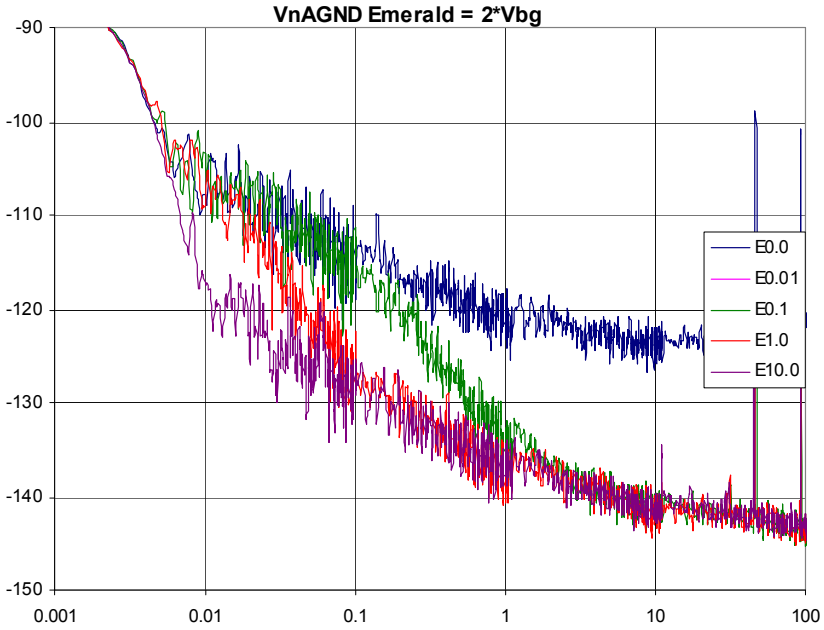


Table 46. 3.3 V AC Operational Amplifier Specifications

Symbol	Description	Min	Typ	Max	Units	Notes
t_{ROA}	Rising Settling Time from 80% of ΔV to 0.1% of ΔV (Active Probe Loading, Unity Gain) Power = Low, Opamp bias = Low Power = Low, Opamp bias = High	 – –	 – –	 3.92 0.72	 µs µs	
t_{SOA}	Falling Settling Time from 20% of ΔV to 0.1% of ΔV (Active Probe Loading, Unity Gain) Power = Low, Opamp bias = Low Power = Medium, Opamp bias = High	 – –	 – –	 5.41 0.72	 µs µs	
SR_{ROA}	Rising Slew Rate (20% to 80%)(Active Probe Loading, Unity Gain) Power = Low, Opamp bias = Low Power = Medium, Opamp bias = High	 0.31 2.7	 – –	 – –	 V/µs V/µs	
SR_{FOA}	Falling Slew Rate (80% to 20%)(Active Probe Loading, Unity Gain) Power = Low, Opamp bias = Low Power = Medium, Opamp bias = High	 0.24 1.8	 – –	 – –	 V/µs V/µs	
BW_{OA}	Gain Bandwidth Product Power = Low, Opamp bias = Low Power = Medium, Opamp bias = High	 0.67 2.8	 – –	 – –	 MHz MHz	
E_{NOA}	Noise at 1 kHz Power = Medium, Opamp bias = High	 –	 100	 –	 nV/rt-Hz	

When bypassed by a capacitor on P2[4], the noise of the analog ground signal distributed to each block is reduced by a factor of up to 5 (14 dB). This is at frequencies above the corner frequency defined by the on-chip 8.1k resistance and the external capacitor.

Figure 14. Typical AGND Noise with P2[4] Bypass



At low frequencies, the opamp noise is proportional to 1/f, power independent, and determined by device geometry. At high frequencies, increased power level reduces the noise spectrum level.

Figure 15. Typical Opamp Noise

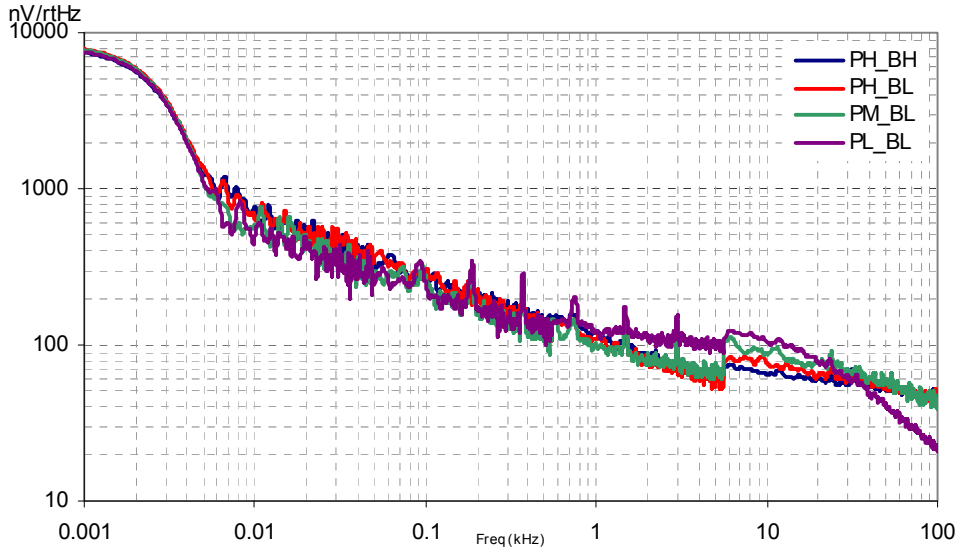


Figure 18. 28-pin SSOP (210 Mils) O28.21 Package Outline, 51-85079

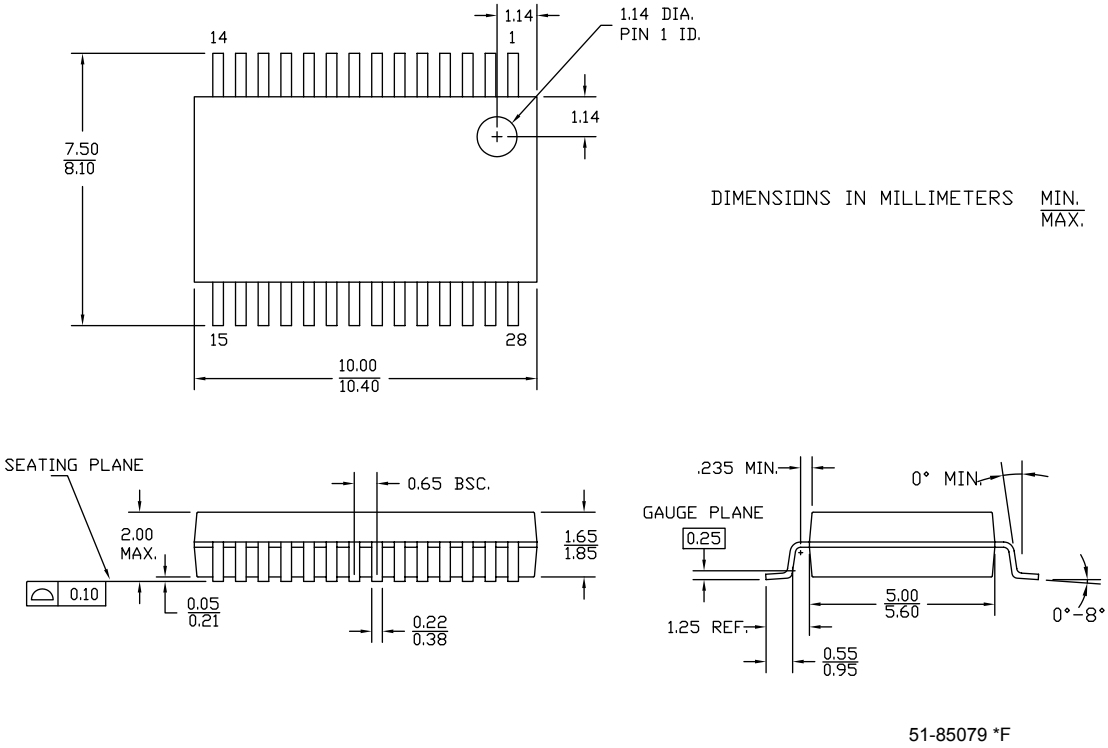


Figure 19. 44-pin TQFP (10 × 10 × 1.4 mm) A44S Package Outline, 51-85064

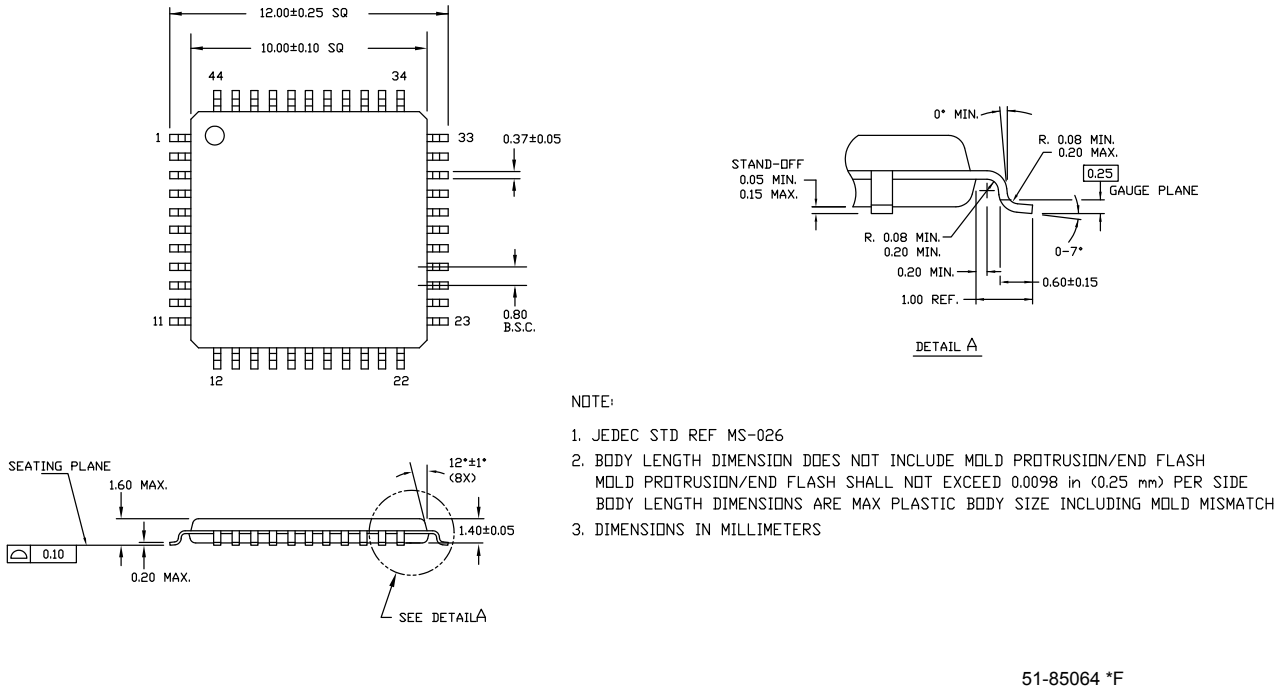
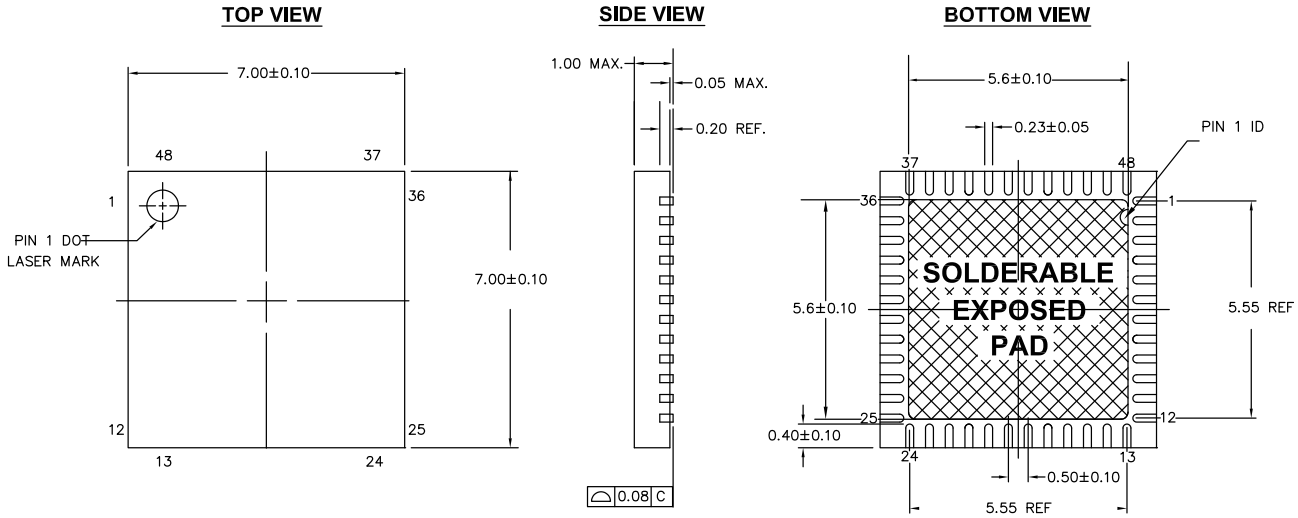


Figure 20. 48-pin QFN (7 × 7 × 1.0 mm) LT48D 5.6 × 5.6 E-Pad (Sawn Type) Package Outline, 001-45616



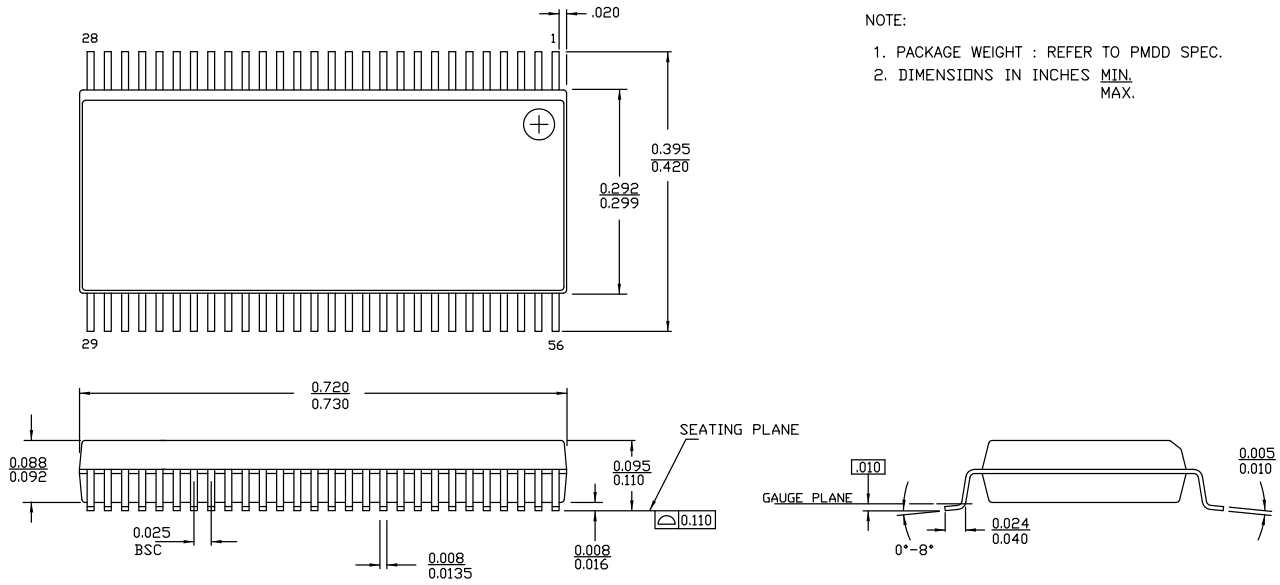
NOTES:
1. ▨ HATCH AREA IS SOLDERABLE EXPOSED METAL.
2. REFERENCE JEDEC#: MO−220
3. PACKAGE WEIGHT: REFER TO PMDD SPEC.
4. ALL DIMENSIONS ARE IN MM [MIN/MAX]
5. PACKAGE CODE

PART #	DESCRIPTION
LT48D	LEAD FREE

001-45616 *E

Important Note For information on the preferred dimensions for mounting QFN packages, see the following application note, *Design Guidelines for Cypress Quad Flat No Extended Lead (QFN) Packaged Devices – AN72845* available at http://www.cypress.com.

Figure 21. 56-pin SSOP (300 Mils) O563 Package Outline, 51-85062



51-85062 *F

Device Programmers

All device programmers can be purchased from the Cypress Online Store.

CY3207ISSP In-System Serial Programmer (ISSP)

The CY3207ISSP is a production programmer. It includes protection circuitry and an industrial case that is more robust than the MiniProg in a production-programming environment.

Note The CY3207ISSP programmer needs the PSoC ISSP software. It is not compatible with the PSoC Programmer software. The latest PSoC ISSP software for this kit can be downloaded from http://www.cypress.com. The kit includes:

- CY3207 Programmer Unit
- PSoC ISSP Software CD
- 110 ~ 240 V Power Supply, Euro-Plug Adapter
- USB 2.0 Cable

Accessories (Emulation and Programming)

Table 60. Emulation and Programming Accessories

Part #	Pin Package	Pod Kit[35]	Foot Kit[36]	Adapter[37]
CY8C28243-24PVXI	20-SSOP	CY3250-28XXX	CY3250-20SSOP-FK	Adapters can be found at http://www.emulation.com.
CY8C28403-24PVXI CY8C28413-24PVXI CY8C28433-24PVXI CY8C28445-24PVXI CY8C28452-24PVXI	28-SSOP	CY3250-28XXX	CY3250-28SSOP-FK	
CY8C28513-24AXI CY8C28545-24AXI	44-TQFP	CY3250-28XXX	CY3250-44TQFP-FK	
CY8C28623-24LTXI CY8C28643-24LTXI CY8C28645-24LTXI	48-QFN	CY3250-28XXXQFN	CY3250-48QFN-FK	

Notes
35. Pod kit contains an emulation pod, a flex-cable (connects the pod to the ICE), two feet, and device samples.
36. Foot kit includes surface mount feet that can be soldered to the target PCB.
37. Programming adapter converts non-DIP package to DIP footprint. Specific details and ordering information for each of the adapters can be found at http://www.emulation.com.